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Inclosure Material:
Plastic
Overall Length:
1.40 millimeters
Terminal Length:
0.40 millimeters
Overall Height:
Between 0.45 millimeters and 0.66 millimeters
Overall Width:
0.60 millimeters
Function For Which Designed:
Bidirectional
End Application:
228, cont csl
Mounting Facility Quantity:
2
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Sod-723 molded package
Mounting Method:
Terminal
Features Provided:
Rohs directive compliance
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
4.7 breakdown voltage, instantaneous
Current Rating Per Characteristic:
0.5 microamperes drain current
Power Rating Per Characteristic:
10.0 watts peak pulse output power
Capacitance Rating In Picofarads:
15.0
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Product Name:
Low capacitance tvs (transient voltage suppressor) array
Terminal Type And Quantity:
2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

